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NPN General Purpose Amplifier (continued)

Symbol	Parameter	Test Conditions	Min	Мах	Units
OFF CHA	RACTERISTICS				
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage*	$I_{\rm C} = 10 \text{ mA}, I_{\rm B} = 0$	40		V
I _{CBO}	Collector Cutoff Current	$V_{CB} = 40 \text{ V}, \text{ I}_{E} = 0$		10	nA
		$V_{CB} = 60 \text{ V}, I_E = 0$		10	μA
EBO	Emitter Cutoff Current	$V_{EB} = 6.0 \text{ V}, I_{C} = 0$		20	nA
V _{BE(on)}	Base-Emitter On Voltage	$V_{CE} = 5.0 \text{ V}, \text{ I}_{C} = 100 \mu\text{A}$ $V_{CE} = 5.0 \text{V}, \text{ I}_{C} = 100 \mu\text{A}$	250 0.45	700 0.65	V
V _{BE(on)}	Base-Emitter On Voltage	02 0 1			V
	,	02 0 1			V
	IGNAL CHARACTERISTICS	$V_{CE} = 5.0 \text{ V}, \text{ I}_{C} = 100 \mu\text{A}$	0.45	0.65	
SMALL S	,	02 0 1			V pF
SMALL S C _{cb}	IGNAL CHARACTERISTICS	$V_{CE} = 5.0 \text{ V}, \text{ I}_{C} = 100 \mu\text{A}$	0.45	0.65	
SMALL S C _{cb} C _{eb}	GIGNAL CHARACTERISTICS	$V_{CE} = 5.0 \text{ V}, \text{ I}_{C} = 100 \mu\text{A}$ $V_{CB} = 5.0 \text{ V}, \text{ f} = 1.0 \text{MHz}$ $V_{EB} = 0.5 \text{ V}, \text{ f} = 1.0 \text{MHz}$ $I_{C} = 100 \mu\text{A}, \text{V}_{CE} = 5.0 \text{V},$	0.45	0.65 4.0 16	pF
SMALL S C _{cb} C _{eb}	IGNAL CHARACTERISTICS Collector-Base Capacitance Emitter-Base Capacitance	$V_{CE} = 5.0 \text{ V}, \text{ I}_{C} = 100 \mu\text{A}$ $V_{CB} = 5.0 \text{V}, \text{ f} = 1.0 \text{MHz}$ $V_{EB} = 0.5 \text{V}, \text{ f} = 1.0 \text{MHz}$ $I_{C} = 100 \mu\text{A}, \text{V}_{CE} = 5.0 \text{V}, \text{ f} = 1.0 \text{kHz}$	0.45	0.65	pF
SMALL S C _{cb} C _{eb}	IGNAL CHARACTERISTICS Collector-Base Capacitance Emitter-Base Capacitance	$V_{CE} = 5.0 \text{ V}, \text{ I}_{C} = 100 \mu\text{A}$ $V_{CB} = 5.0 \text{V}, \text{ f} = 1.0 \text{MHz}$ $V_{EB} = 0.5 \text{V}, \text{ f} = 1.0 \text{MHz}$ $I_{C} = 100 \mu\text{A}, \text{V}_{CE} = 5.0 \text{V}, \text{ f} = 1.0 \text{kHz}$ $I_{C} = 10 \text{mA}, \text{V}_{CE} = 5.0 \text{V}, $	1.0 250	0.65 4.0 16	pF
SMALL S C _{cb} C _{eb} h _{fe}	GIGNAL CHARACTERISTICS Collector-Base Capacitance Emitter-Base Capacitance Small-Signal Current Gain	$V_{CE} = 5.0 \text{ V}, \text{ I}_{C} = 100 \mu\text{A}$ $V_{CB} = 5.0 \text{ V}, \text{ I}_{C} = 100 \mu\text{A}$ $V_{EB} = 0.5 \text{ V}, \text{ I} = 1.0 \text{MHz}$ $I_{C} = 100 \mu\text{A}, \text{V}_{CE} = 5.0 \text{V}, \text{f} = 1.0 \text{kHz}$ $I_{C} = 10 \text{mA}, \text{V}_{CE} = 5.0 \text{V}, \text{f} = 100 \text{MHz}$	0.45	0.65 4.0 16	pF
SMALL S C _{cb} C _{eb} h _{fe}	IGNAL CHARACTERISTICS Collector-Base Capacitance Emitter-Base Capacitance	$V_{CE} = 5.0 \text{ V}, \text{ I}_{C} = 100 \mu\text{A}$ $V_{CB} = 5.0 \text{V}, \text{ f} = 1.0 \text{MHz}$ $V_{EB} = 0.5 \text{V}, \text{ f} = 1.0 \text{MHz}$ $I_{C} = 100 \mu\text{A}, \text{V}_{CE} = 5.0 \text{V}, \text{ f} = 1.0 \text{kHz}$ $I_{C} = 10 \text{mA}, \text{V}_{CE} = 5.0 \text{V}, $	1.0 250	0.65 4.0 16	pF
SMALL S C _{cb} C _{eb} h _{fe}	GIGNAL CHARACTERISTICS Collector-Base Capacitance Emitter-Base Capacitance Small-Signal Current Gain	$V_{CE} = 5.0 \text{ V}, \text{ I}_{C} = 100 \mu\text{A}$ $V_{CB} = 5.0 \text{ V}, \text{ I}_{C} = 100 \mu\text{A}$ $V_{EB} = 0.5 \text{ V}, \text{ I} = 1.0 \text{MHz}$ $I_{C} = 100 \mu\text{A}, \text{V}_{CE} = 5.0 \text{V}, \text{I} = 1.0 \text{Hz}$ $I_{C} = 10 \text{mA}, \text{V}_{CE} = 5.0 \text{V}, \text{I} = 100 \text{MHz}$ $V_{CE} = 5.0 \text{V}, \text{I}_{C} = 30 \mu\text{A}, $	1.0 250	0.65 4.0 16	pF
V _{BE(on)} SMALL S C _{cb} C _{eb} h _{fe}	GIGNAL CHARACTERISTICS Collector-Base Capacitance Emitter-Base Capacitance Small-Signal Current Gain	$V_{CE} = 5.0 \text{ V}, \text{ I}_{C} = 100 \mu\text{A}$ $V_{CB} = 5.0 \text{ V}, \text{ I}_{C} = 100 \mu\text{A}$ $V_{EB} = 0.5 \text{ V}, \text{ I} = 1.0 \text{MHz}$ $I_{C} = 100 \mu\text{A}, \text{V}_{CE} = 5.0 \text{V}, \text{f} = 1.0 \text{kHz}$ $I_{C} = 10 \text{mA}, \text{V}_{CE} = 5.0 \text{V}, \text{f} = 100 \text{MHz}$	1.0 250	0.65 4.0 16	p

*Pulse Test: Pulse Width \leq 300 $\mu s,$ Duty Cycle \leq 2.0%

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